



ATP404

N-Channel Power MOSFET 60V, 95A, 7.2mΩ, ATPAK

ON Semiconductor®

<http://onsemi.com>

Features

- ON-resistance $R_{DS(on)1}=5.5m\Omega$ (typ.)
- 4.5V drive
- Input capacitance $C_{iss}=6400pF$ (typ.)
- Halogen free compliance

Specifications

Absolute Maximum Ratings at $T_a=25^\circ C$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		60	V
Gate-to-Source Voltage	V_{GSS}		± 20	V
Drain Current (DC)	I_D		95	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	380	A
Allowable Power Dissipation	P_D	$T_c=25^\circ C$	70	W
Channel Temperature	T_{ch}		150	$^\circ C$
Storage Temperature	T_{stg}		-55 to +150	$^\circ C$
Avalanche Energy (Single Pulse) *1	E_{AS}		214	mJ
Avalanche Current *2	I_{AV}		48	A

Note : *1 $V_{DD}=30V$, $L=100\mu H$, $I_{AV}=48A$

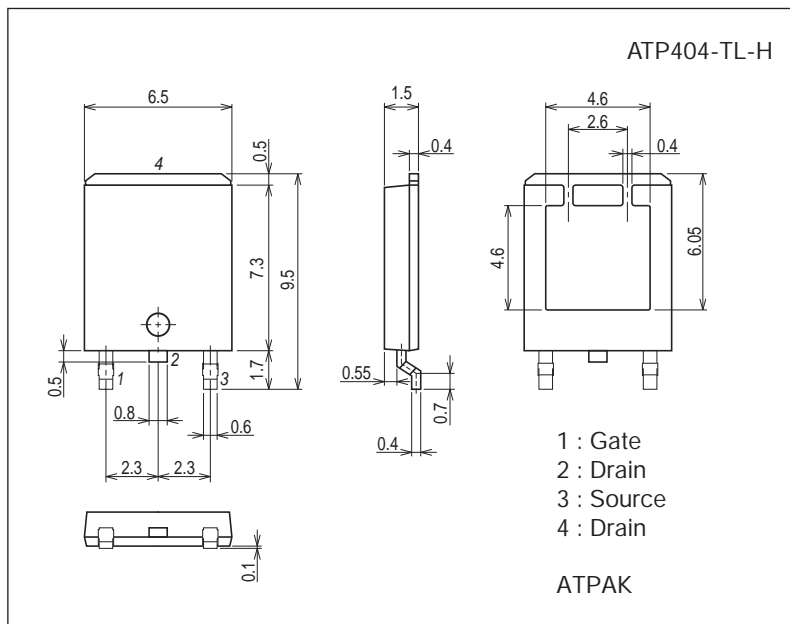
*2 $L \leq 100\mu H$, Single pulse

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

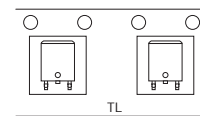
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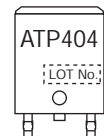
Product & Package Information

- Package : ATPAK
- JEITA, JEDEC : -
- Minimum Packing Quantity : 3,000 pcs./reel

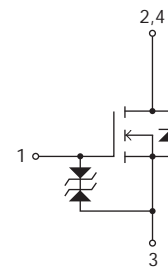
Packing Type: TL



Marking



Electrical Connection

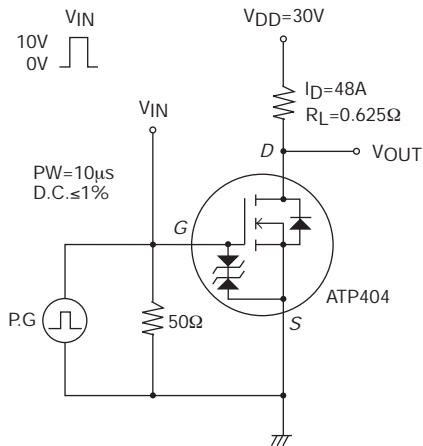


ATP404

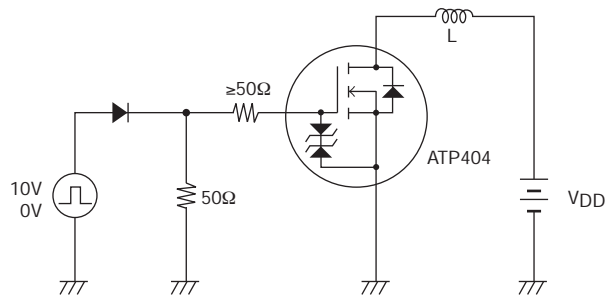
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0V	60			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V			10	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±16V, V _{DS} =0V			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	y _{fs}	V _{DS} =10V, I _D =48A		100		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =48A, V _{GS} =10V		5.5	7.2	mΩ
	R _{DS(on)2}	I _D =48A, V _{GS} =4.5V		7.5	10.5	mΩ
Input Capacitance	C _{iss}	V _{DS} =20V, f=1MHz		6400		pF
Output Capacitance	C _{oss}			490		pF
Reverse Transfer Capacitance	C _{rss}			380		pF
Turn-ON Delay Time	t _{d(on)}			53		ns
Rise Time	t _r	See specified Test Circuit.		640		ns
Turn-OFF Delay Time	t _{d(off)}			380		ns
Fall Time	t _f			520		ns
Total Gate Charge	Q _g			120		nC
Gate-to-Source Charge	Q _{gs}	V _{DS} =30V, V _{GS} =10V, I _D =95A		25		nC
Gate-to-Drain "Miller" Charge	Q _{gd}			25		nC
Diode Forward Voltage	V _{SD}		I _S =95A, V _{GS} =0V		0.95	1.2

Switching Time Test Circuit

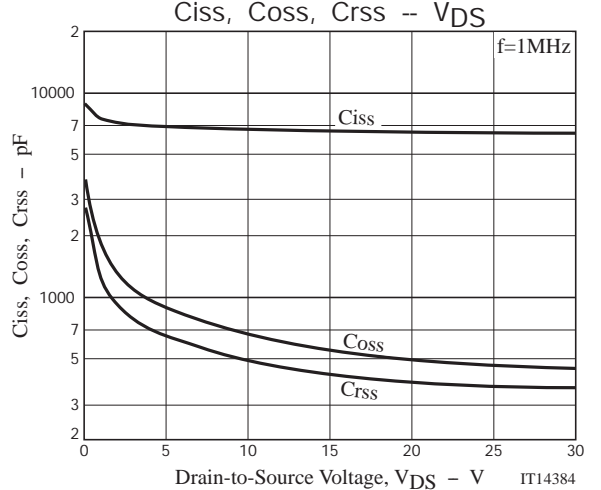
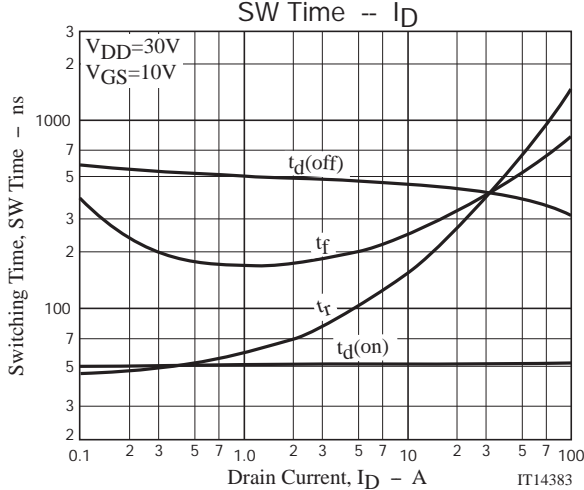
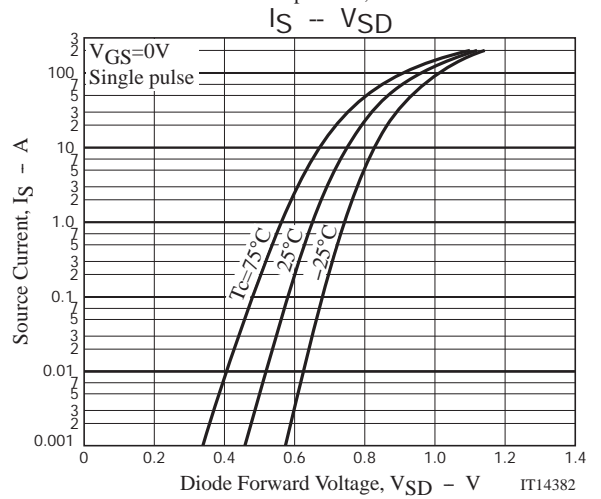
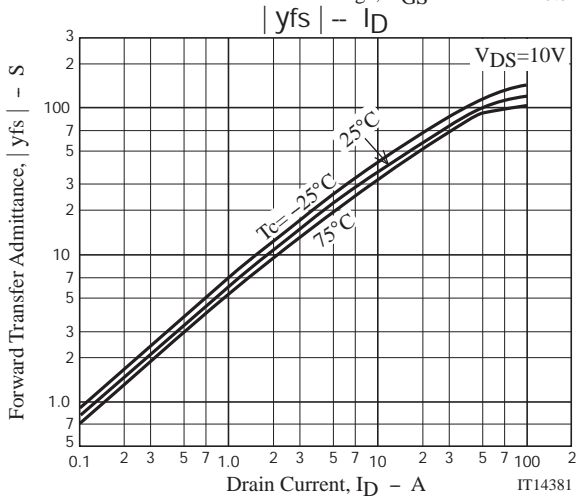
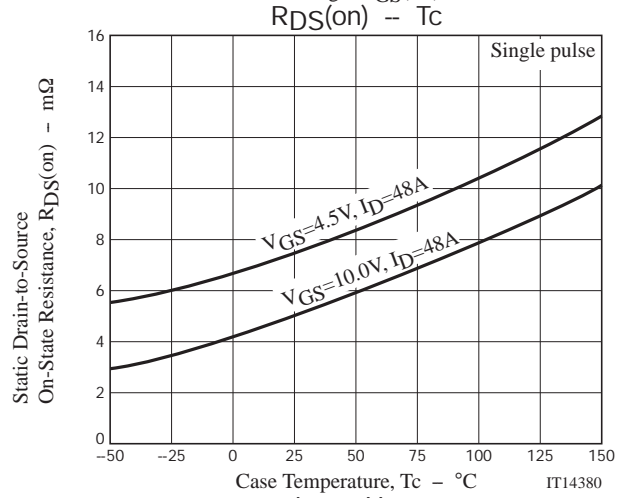
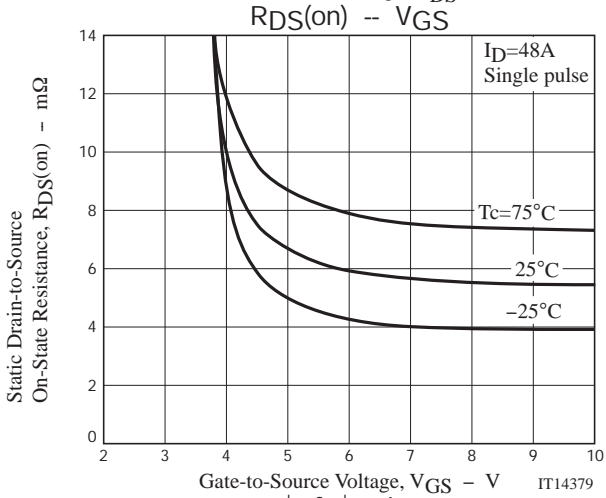
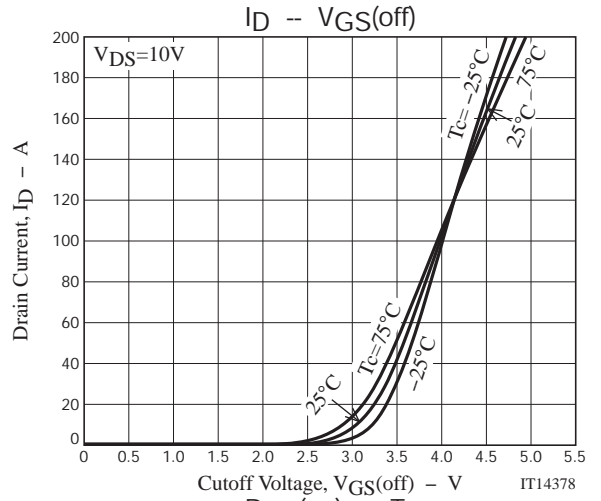
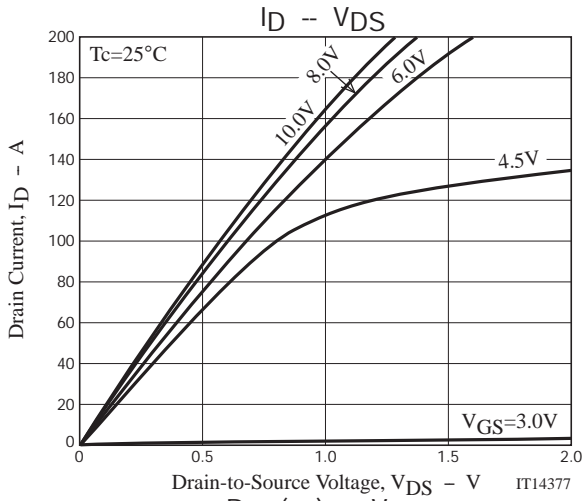


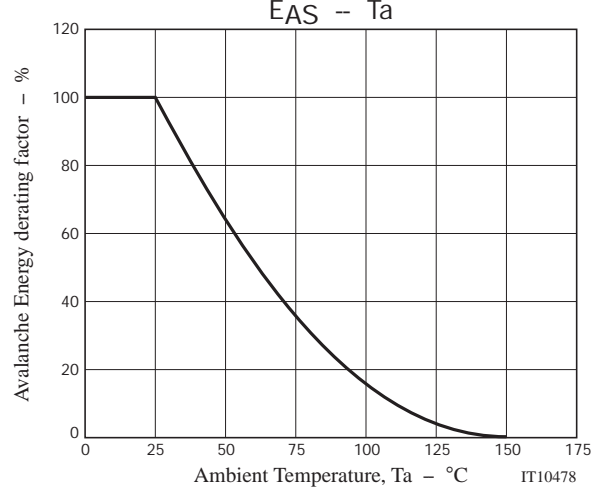
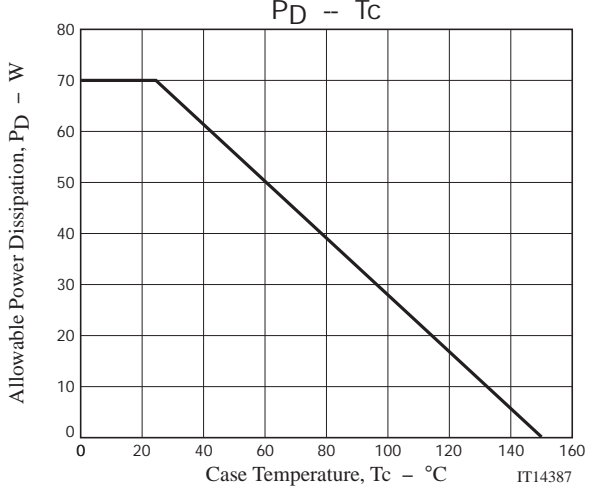
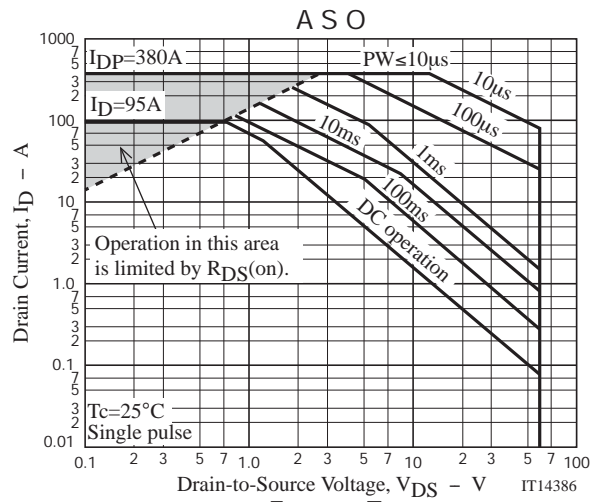
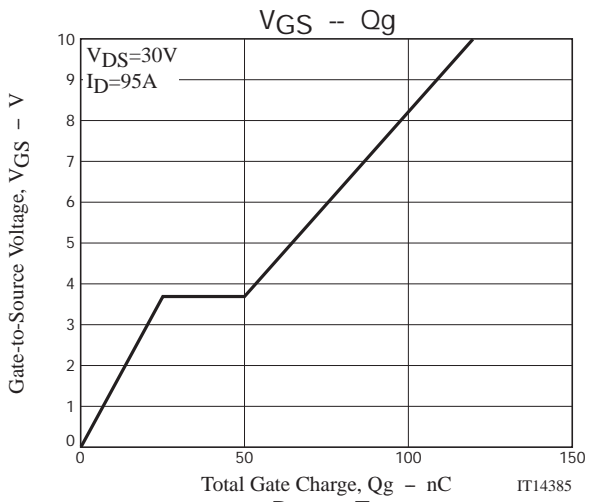
Avalanche Resistance Test Circuit



Ordering Information

Device	Package	Shipping	memo
ATP404-TL-H	ATPAK	3,000pcs./reel	Pb Free and Halogen Free





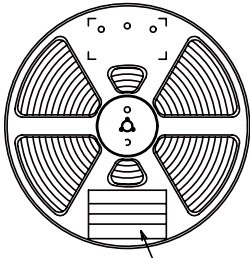
Taping Specification

ATP404-TL-H

1. Packing Format (TL)

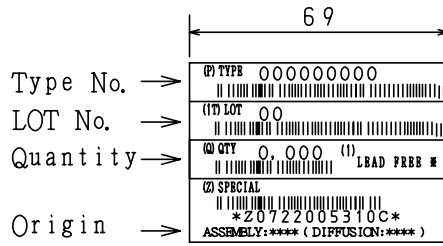
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	INNER BOX SD-C-18	OUTER BOX SD-A-18
ATPAK	ATP	3,000	3,000	15,000	1 reels contained Dimensions:mm (external) 340×340×28	5 inner boxes contained Dimensions:mm (external) 355×355×165

Packing method



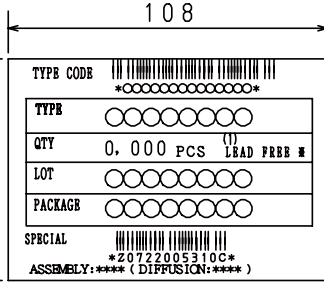
Reel label

Reel label, Inner box label
(unit:mm)



Outer box label

It is a label at the time of factory shipments. The form of a label may change in physical distribution process.



NOTE (1)

The LEAD FREE # description shows that the surface treatment of the terminal is lead free.

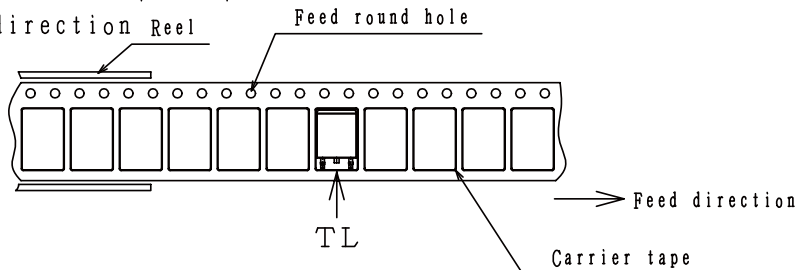
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction Reel



The one electrode terminals on feed hole side...TL

ATP404

Outline Drawing

ATP404-TL-H



Land Pattern Example



Note on usage : Since the ATP404 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.